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PATENT  
0247D-5385

GP2812  
Mar  
3-20

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

Hiroyuki Kinoshita et al.

Serial No: 08/808,315

Filed: February 28, 1997

For: Sapphire Monocrystal, Semiconductor  
Laser Diode Using the Same for  
Substrate, and Method for  
Manufacturing the Same

Art Unit: 2812

Examiner: Joni Y. Chang

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OPL  
6-2-99

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Date

William H. Wright 3/10/99

**RESPONSE TO RESTRICTION REQUIREMENT**

Assistant Commissioner for Patents  
Washington, D.C. 20231

Dear Sir:

In response to the Restriction Requirement dated February 11, 1999, Applicant elects for prosecution the claims of Group I, 1-8. Please cancel claims 9-16 without prejudice.

Respectfully submitted,

LOEB & LOEB LLP

By:

William H. Wright

Registration No. 36,312

Attorney for Applicant(s)

Date: 3/10/99

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